

20A 45V Planar Schottky Diode
■ Applications

Device optimized for low forward voltage drop to maximize efficiency in Power Supply applications

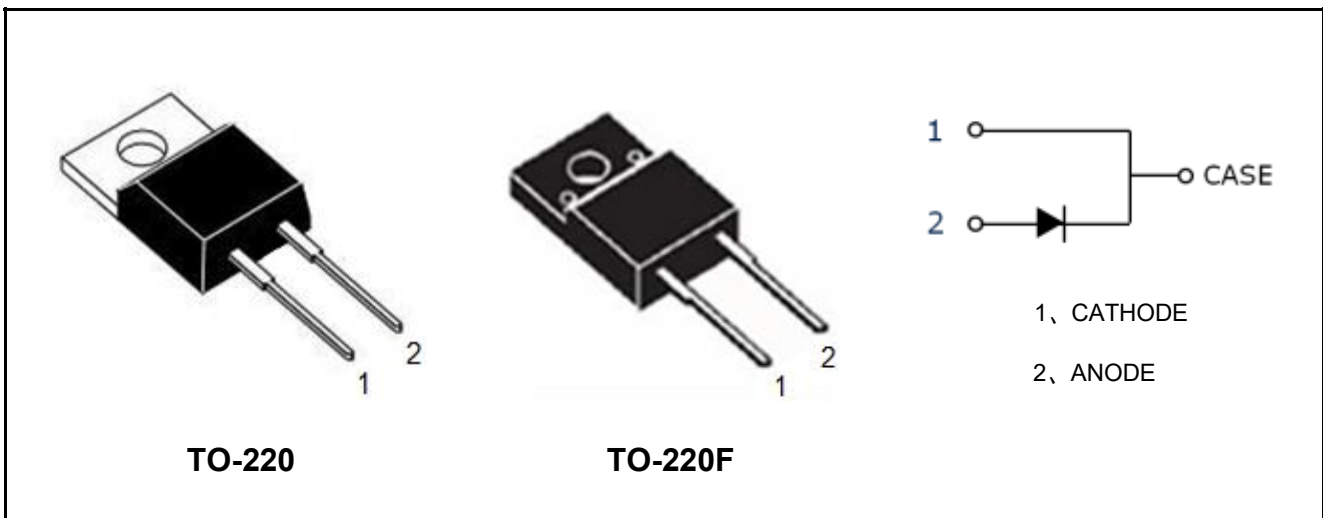
- AC-DC Adaptors
- DC-DC Converters

■ Features

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss,High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- Halogen Free and RoHS Compliant

■ Product Summary

V_{RRM}	45	V
$I_F@T_J=25^{\circ}C$	20	A
$V_{F,TYP}@10A,T_J=25^{\circ}C$	0.65	V
$V_{F,TYP}@10A,T_J=125^{\circ}C$	0.57	V
$I_{R,TYP}@T_J=25^{\circ}C$	0.1	mA



Marking	Package	Packaging	Min. package quantity
MBR2045	TO-220	Tube	1000
MBR2045	TO-220F	Tube	1000



■ Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Parameter	Symbol	Ratings	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	45	V
Surge Peak Reverse Voltage	V_{RSM}		V
DC Peak Blocking Voltage	V_R		V
Continuous Forward Current	$I_{F(per\ leg)}$	20	A
	$I_{F(total)}$	20	A
Non-Repetitive Peak Surge Current((Surge applied at rated load conditions halfwave,single phase,60HZ)	I_{FSM}	200	A
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-65-150	°C

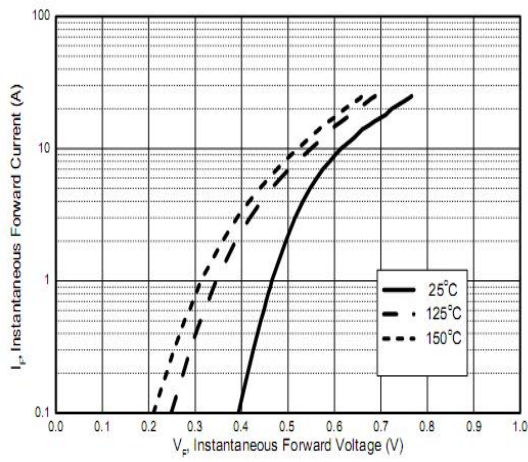
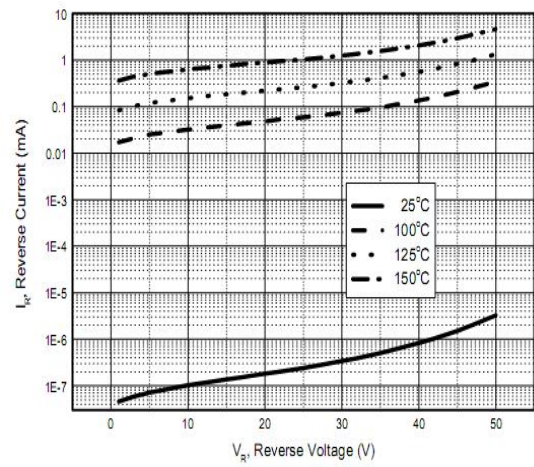
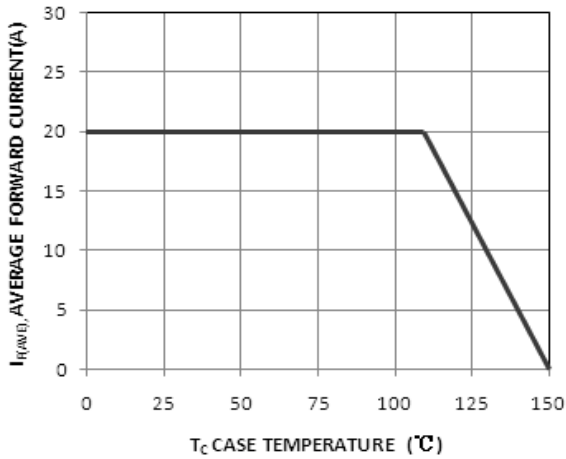
■ Thermal Characteristics

Parameter	Symbol	Package	Max	Unit
Maximum Junction-to-Case	$R_{\theta JC}$	TO-220	2	°C/W
	$R_{\theta JC}$	TO-220F	4	°C/W
Maximum Junction-to-Ambient	$R_{\theta JA}$	TO-220	60	°C/W
	$R_{\theta JA}$	TO-220F	60	°C/W

■ Electrical Characteristics (Per Leg) (Tc=25°C unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=10A, T_J=25^\circ C$	-	0.65	-	V
		$I_F=10A, T_J=125^\circ C$	-	0.57	-	V
Reverse Current	I_R	$V_R=45V, T_J=25^\circ C$	-	0.1	-	mA
		$V_R=45V, T_J=125^\circ C$	-	15	-	mA



■ Characteristics Curves

Forward Characteristics Per Diode

Reverse Characteristics Per Diode

Current Derating Per Diode


■ Reflow Soldering Temperature Profile